NSN 5961-01-273-3053

Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-273-3053 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.9 regulator voltage **Current Rating Per Characteristic:** 640.00 milliamperes all primaries horsepower metric and 2.44 amperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-prf-19500/124 government specification Shelf Life: N/a **Unit Of Measure:**

A110a0

No Fiig:

Demilitarization:

NSN 5961-01-273-3053

Diode Semiconductor Device - Page 2 of 2



Mil-std (military Standard):

Mil-prf-19500 spec.